

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

MCH6544 — NPN Epitaxial Planar Silicon Transistor Inverter Circuit / Driver Applications

Applicaitons

· Relay drivers, lamp drivers, motor drivers

Features

- · Composite type with an NPN transistor contained in one package facilitating high-density mounting
- · Ultrasmall package facilitates miniaturization in end products

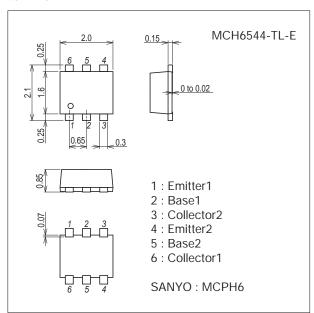
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		60	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	V _{EBO}		5	V
Collector Current	IC		500	mA
Collector Current (Pulse)	ICP		1.5	Α
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.5	W
Total Power Dissipation	PT	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.55	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7022A-011



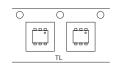
Product & Package Information

• Package : MCPH6

• JEITA, JEDEC : SC-88, SC-70-6, SOT-363

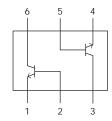
• Minimum Packing Quantity : 3,000 pcs./reel

Packing Type : TL Marking





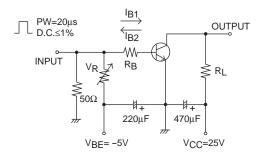
Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit	
Parameter	Symbol Conditions		min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0A			100	nA	
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA	
DC Current Gain	hFE	V _{CE} =2V, I _C =10mA	300		800		
Gain-Bandwidth Product	fŢ	V _{CE} =10V, I _C =50mA		500		MHz	
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		2.8		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =100mA, I _B =10mA		50	100	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =100mA, I _B =10mA		0.9	1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	60			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0A	5			V	
Turn-ON Time	ton			30		ns	
Storage Time	t _{stg}	See specified Test Circuit.		340		ns	
Fall Time	t _f			55		ns	

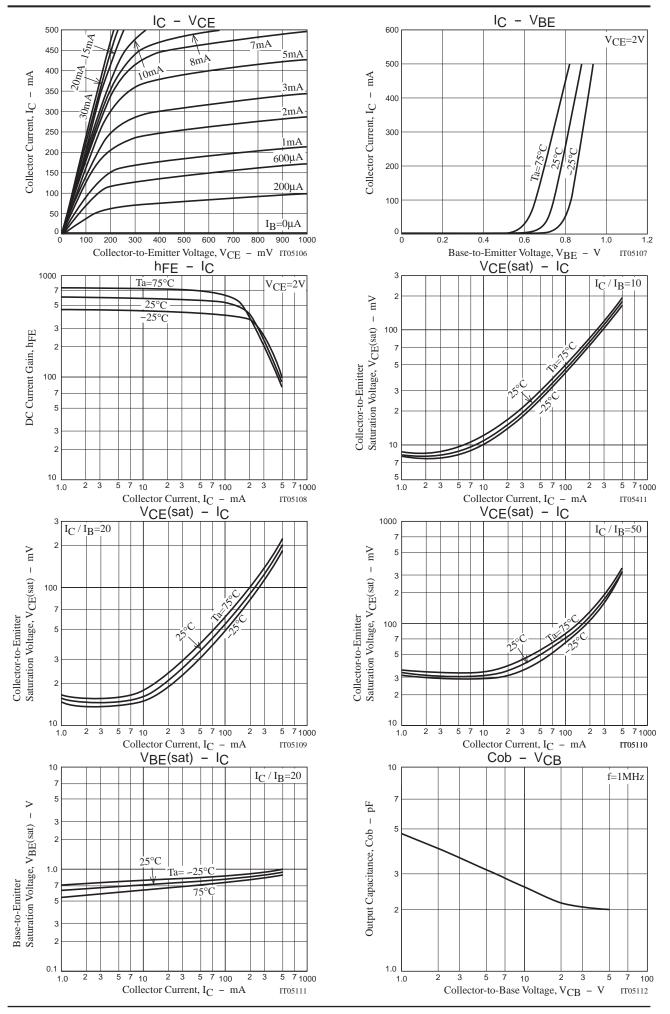
Switching Time Test Circuit

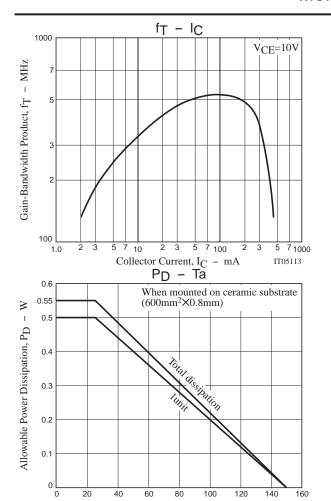


 $I_{C}=20I_{B1}=-20I_{B2}=200mA$

Ordering Information

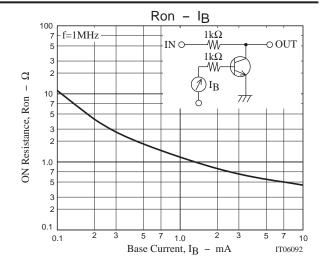
Device	Package	Shipping	memo
MCH6544-TL-E	МСРН6	3,000pcs./reel	Pb Free





Ambient Temperature, Ta - °C

IT10744

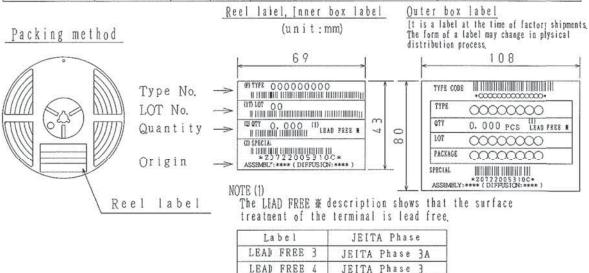


Embossed Taping Specification

MCH6544-TL-E

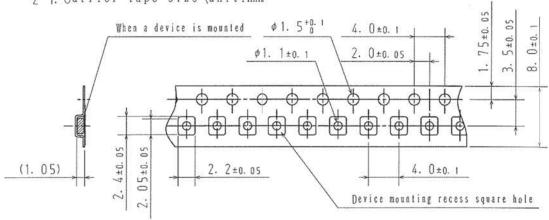
1. Packing Format

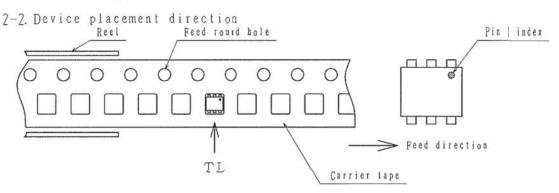
Package Name	Carrier Tape Type	Maximum Number of devices contained (yes)			Packing format		
		Reel	[nner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
МСРН6	MCP4	3, 000	15, 000	90, 000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210	



2. Taping configuration

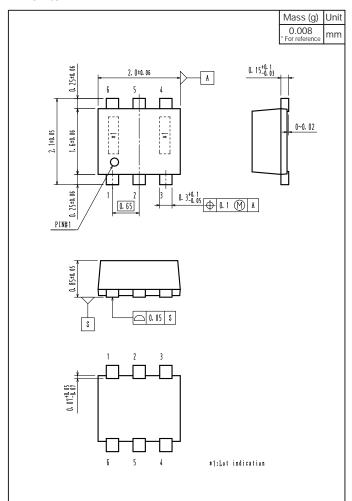
2-1. Carrier tape size (unit:mm)



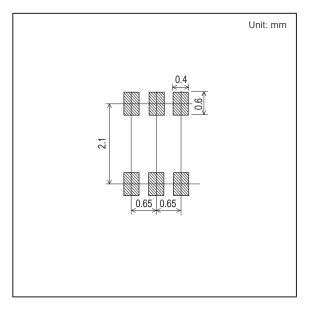


Those with pin 1 index on the feed hole side ·····TL

Outline Drawing MCH6544-TL-E



Land Pattern Example



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